**Product data sheet** 

## 1. General description

NPN medium power transistor in an ultra thin SOT1061 leadless small Surface-Mounted Device (SMD) plastic package.

**Table 1. Product overview** 

Type number	Package	Package		
	Nexperia	JEITA		
BC55PA	SOT1061	-	BC52PA	
BC55-10PA			BC52-10PA	
BC55-16PA			BC52-16PA	

### 2. Features and benefits

- High current
- · Three current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity
- Leadless very small SMD plastic package with medium power capability
- AEC-Q101 qualified

# 3. Applications

- Linear voltage regulators
- Power management
- Low-side switches
- MOSFET drivers
- · Battery-driven devices
- Amplifiers

### 4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base		-	-	60	V
I <sub>C</sub>	collector current			-	-	1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	2	А
h <sub>FE</sub>	DC current gain						
	BC55PA	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA T <sub>amb</sub> = 25 °C	[1]	63	-	250	
	BC55-10PA		[1]	63	-	160	
	BC55-16PA		[1]	100	-	250	

[1] pulsed;  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 



60 V, 1 A NPN medium power transistors

# 5. Pinning information

#### **Table 3. Pinning**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	С
2	E	emitter		5
3	С	collector		B—
				Ė
			1 2	sym021
			Transparent top view	

# 6. Ordering information

#### **Table 4. Ordering information**

Type number	Package	Package					
	Name	Description	Version				
BC55PA	HUSON3	plastic surface-mounted package; exposed	SOT1061				
BC55-10PA		die pad for good heat transfer; 3 leads					
BC55-16PA							

# 7. Marking

#### Table 5. Marking

Type number	Marking code
BC55PA	AW
BC55-10PA	ВН
BC55-16PA	ВЈ

#### 60 V, 1 A NPN medium power transistors

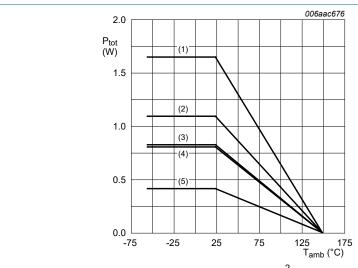
# 8. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	open emitter		60	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	60	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V
I <sub>C</sub>	collector current			-	1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	2	Α
I <sub>B</sub>	base current				0.3	Α
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	0.3	Α
P <sub>tot</sub> total pov	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	0.42	W
			[2]	-	0.83	W
			[3]	-	1.10	W
			[4]	-	0.81	W
			[5]	-	1.65	W
T <sub>j</sub>	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 6 cm<sup>2</sup>.
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.



- (1) FR4 PCB, 4-layer copper, mounting pad for collector 1 cm<sup>2</sup>
- (2) FR4 PCB, single-sided copper, mounting pad for collector 6 cm<sup>2</sup>
- (3) FR4 PCB, single-sided copper, mounting pad for collector 1 cm<sup>2</sup>
- (4) FR4 PCB, 4-layer copper, standard footprint
- (5) FR4 PCB, single-sided copper, standard footprint

Fig. 1. Power derating curves SOT89

**Product data sheet** 

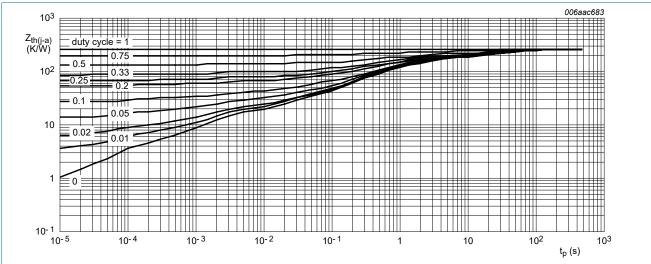
#### 60 V, 1 A NPN medium power transistors

### 9. Thermal characteristics

**Table 7. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	298	K/W
		[2]	-	-	151	K/W	
			[3]	-	-	114	K/W
			[4]	-	-	154	K/W
			[5]	-	-	76	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	20	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 6 cm<sup>2</sup>.
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

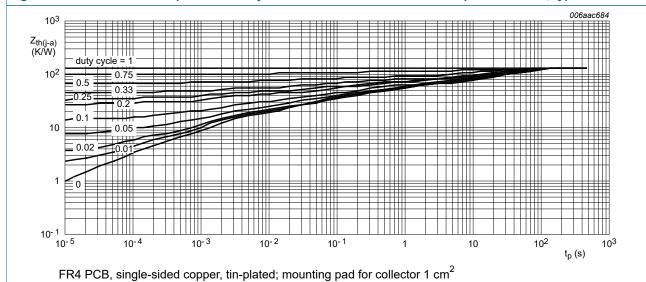
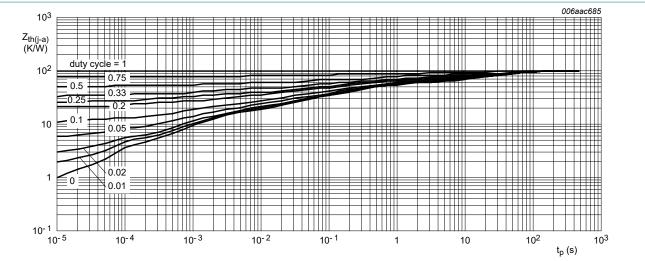


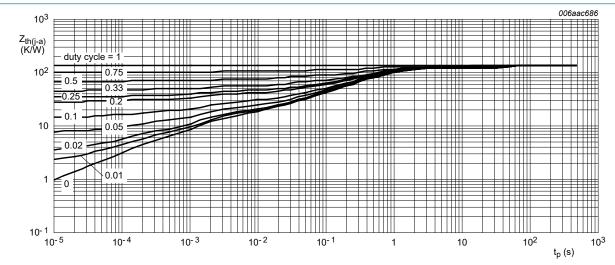
Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

#### 60 V, 1 A NPN medium power transistors



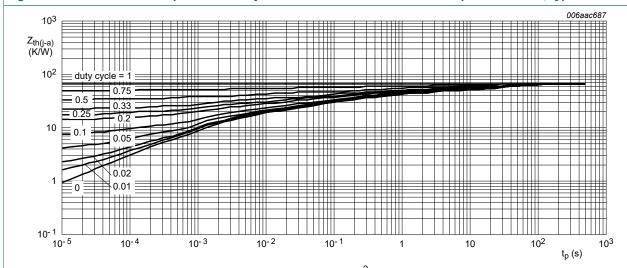
FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 6 cm<sup>2</sup>

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer copper, standard footprint

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer copper, mounting pad for collector 1 cm<sup>2</sup>.

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

### 60 V, 1 A NPN medium power transistors

# 10. Characteristics

#### **Table 8. Characteristics**

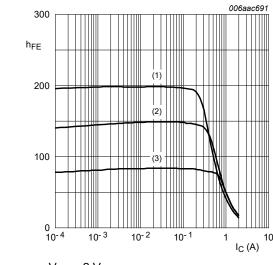
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	$I_C = 100 \mu A; I_E = 0; T_{amb} = 25 °C$		60	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	I <sub>C</sub> = 2 μA; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C	$I_C = 2 \mu A; I_B = 0 A; T_{amb} = 25 °C$ 60				V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage	I <sub>C</sub> = 0 A; I <sub>E</sub> = 100 μA		5	-	-	V
I <sub>CBO</sub>	collector-base	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
	cut-off current	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
h <sub>FE</sub>	DC current gain						<b>'</b>
	BC55PA	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	-	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	250	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	40	-	-	
	BC55-10PA	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	-	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	160	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	40	-	-	
	BC55-16PA	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	-	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA; T <sub>amb</sub> = 25 °C	[1]	100	-	250	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	40	-	-	
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	-	
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	40	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA; T <sub>amb</sub> = 25 °C [1] -		-	-	0.5	V
V <sub>BE</sub>	base-emitter voltage	$V_{CE} = 2 \text{ V}; I_{C} = 500 \text{ mA}; T_{amb} = 25 \text{ °C}$ [1]		-	-	1	V
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = I_e = 0 \text{ A}; f = 1 \text{ MHz}; - 6$ $T_{amb} = 25 \text{ °C}$			6	-	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 50 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C		100	180	-	MHz

<sup>[1]</sup> pulsed;  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

**Product data sheet** 

6 / 12

### 60 V, 1 A NPN medium power transistors



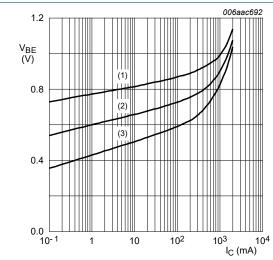
$$V_{CE} = 2 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55$$
 °C

Fig. 7. DC current gain as a function of collector current; typical values



$$V_{CE} = 2 V$$

(1) 
$$T_{amb} = -55$$
 °C

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb}$$
 = 100 °C

Fig. 9. Base-emitter voltage as a function of collector current; typical values

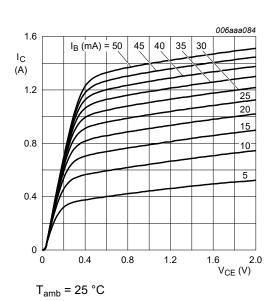
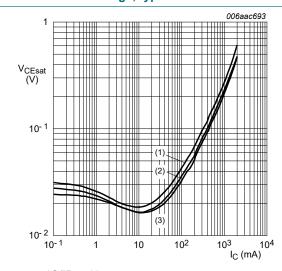


Fig. 8. Collector current as a function of collectoremitter voltage; typical values



(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. Collector-emitter saturation voltage as a function of collector current; typical values

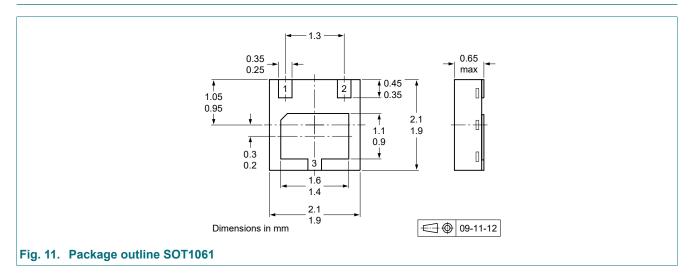
60 V, 1 A NPN medium power transistors

## 11. Test information

## 11.1. Quality information

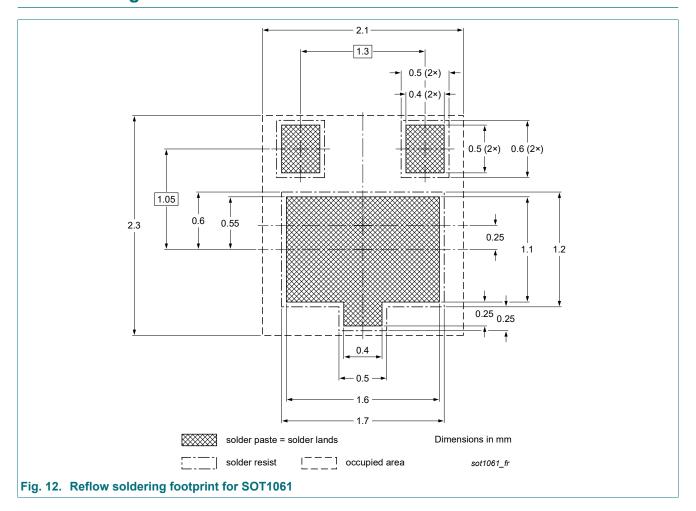
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

# 12. Package outline



### 60 V, 1 A NPN medium power transistors

# 13. Soldering



### 60 V, 1 A NPN medium power transistors

# 14. Revision history

#### Table 9. Revision history

Table 9. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BC55PA_SER v.9	20220701	Product data sheet	-	BCP55_BCX55_BC55PA v.8		
Modifications:	<ul> <li>Series data sheet describing several packages reduced to series data sheets per package.</li> <li>Package information removed.</li> </ul>					
BCP55_BCX55_BC55PA v.8	20111024	Product data sheet	-	BC637_BCP55_BCX55 v.7		
BC637_BCP55_BCX55 v.7	20070625	Product data sheet	-	BC637_BCP55_BCX55 v.6		
BC637_BCP55_BCX55 v.6	20050218	Product data sheet	CPCN200405029	BC635_637_639 v.4 BCP54_55_56 v.5 BCX54_55_56 v.4		
BC635_637_639 v.4	20011010	Product Specification	-	BC635_637_639 v.3		
BCP54_55_56 v.5	20030206	Product Specification	-	BCX54_55_56 v.4		
BCX54_55_56 v.4	20011010	Product Specification	-	BCX54_55_56 v.3		

# 60 V, 1 A NPN medium power transistors

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- 2] The term 'short data sheet' is explained in section "Definitions".
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